Fluorine doped Fe$_2$O$_3$ nanostructures by a one-pot plasma-assisted strategy†

G. Carraro,$^a$ A. Gasparotto,$^a$ C. Maccato,$^a$ E. Bontempi,$^b$ O. I. Lebedev,$^c$ S. Turner,$^d$ C. Sada,$^e$ L. E. Depero,$^b$ G. Van Tendeloo$^d$ and D. Barreca$^*$$^f$

The present work reports on the synthesis of fluorine doped Fe$_2$O$_3$ nanomaterials by a single-step plasma enhanced-chemical vapor deposition (PE-CVD) strategy. In particular, Fe(hfa)$_2$TMEDA (hfa = 1,1,5,5,5-hexafluoro-2,4-pentanedionato; TMEDA = N,N,N',N'-tetramethylethylenediamine) was used as molecular source for both Fe and F in Ar/O$_2$ plasmas. The structure, morphology and chemical composition of the synthesized nanosystems were thoroughly analyzed by two-dimensional X-ray diffraction (XRD$^2$), field emission-scanning electron microscopy (FE-SEM), X-ray photoelectron spectroscopy (XPS), secondary ion mass spectrometry (SIMS) and transmission electron microscopy (TEM). A suitable choice of processing parameters enabled the selective formation of $\alpha$-Fe$_2$O$_3$ nanomaterials, characterized by an homogeneous F doping, even at 100 °C. Interestingly, a simultaneous control of the system nanoscale organization and fluorine content could be achieved by varying the sole growth temperature. The tailored properties of the resulting materials can be favourably exploited for several technological applications, ranging from photocatalysis, to photoelectrochemical cells and gas sensing.

1. Introduction

Over the last decade, Fe$_2$O$_3$ has undoubtedly been one of the most investigated metal oxides, due to its abundance, non-toxicity and multi-functional properties. In particular, nano-scale Fe$_2$O$_3$ systems hold significant promise for magnetic, electrochemical and photocatalytic applications. Among the various iron(III) oxide polymorphs, $\alpha$-Fe$_2$O$_3$ (hematite), the most stable one, is an attractive candidate for photocatalytic and photoelectrochemical water splitting promoted by solar radiation, due to its suitable band gap ($E_g \approx 2.2$ eV), chemical stability and low cost. Nevertheless, $\alpha$-Fe$_2$O$_3$ materials suffer from some disadvantages – such as high resistivity and fast recombinaction of photogenerated electrons/holes – which, in spite of several efforts, are far from being completely overcome. To this regard, the ability to develop and process iron oxide-based systems with controlled nano-organization plays a key role for the fabrication of advanced nanodevices. So far, several preparation strategies have been adopted for the synthesis of Fe$_2$O$_3$ nanosystems, such as hydrothermal approaches,$^5,12,22$ ballistic deposition,$^3,20$ sol-gel,$^2$ spray pyrolysis,$^6,19$ electrochemical routes,$^17$ atomic layer deposition$^14$ and chemical vapor deposition (CVD). Along with the preparation route, further degrees of freedom to control Fe$_2$O$_3$ nanosystem properties are offered by its doping with suitable elements.$^4,18$ To date, several examples regarding the introduction of cationic dopants into hematite are available in the literature,$^5,6,15,20,22,24$ whereas the use of anionic dopants, such as fluorine, deserves further attention. As a matter of fact, F introduction in metal oxides can boost various beneficial effects, favorably affecting the material functional performances due to the concurrence of different phenomena.$^25,26$ In particular, the passivation of surface defects by fluorine can prevent the detrimental recombination of photogenerated electrons and holes, resulting in a higher charge carrier lifetime. Furthermore, F doping of oxide matrices might increase both the system electrical conductivity and absorption coefficient. The latter phenomenon, in turn, produces an improved light harvesting, of great importance for photoactivated applications. Last but not least, the substitution of O by F increases the Lewis acidity of iron centers, due to the electron withdrawing effect exerted by fluorine, enhancing thus the system catalytic activity.$^{25,30}$ Yet, in spite of these advantageous effects, F-doping of iron oxide photocatalysts has never been reported in the literature up to date.

Among the various approaches, PE-CVD has been shown to be a powerful synthetic tool for the control of material structure, morphology and composition. Besides providing an
inherent flexibility for the low-temperature growth of nanostructures with unique features, the use of non-equilibrium cold plasmas offers attractive possibilities for an in situ doping of the growing systems, due to the generation of fluorinated radicals in the plasma environment. In particular, in this work we propose an amenable approach for the in situ synthesis and simultaneous F doping of hematite, involving the PE-CVD of \( \alpha \)-Fe\(_2\)O\(_3\) from Fe(hfa)\(_2\)TMEDA in Ar/O\(_2\) plasmas at 100–400 °C. Under these conditions, the adopted compound acts as a "single-source" precursor for both Fe and F, allowing to conveniently avoid the use of corrosive and/or toxic reactants (such as CF\(_4\), F\(_2\), NH\(_4\)F,...) and to prevent thermal stress/cracking phenomena occurring at higher temperatures. Relevant results concerning the system chemico-physical features show that the obtained iron oxide materials present a controlled nano-organization, as well as a fluorine content directly dependent on the adopted growth temperature.

2. Experimental

2.1. Synthesis

The iron(II) molecular precursor Fe(hfa)\(_2\)TMEDA was synthesized following a recently reported literature procedure. Single-source Si(100) substrates (1.5 \( \times \) 1.5 cm\(^2\)) were purchased from MEMC (Merano, Italy). Prior to deposition, the substrates were cleaned by iterative dipping in a sulphonic detergent solution, deionized water and isopropyl alcohol, and finally dried under an Ar flow.

Growth experiments were carried out in Ar/O\(_2\) plasmas (flow rates = 15 and 20 sccm), respectively, using a custom-built two-electrode radio frequency (RF, \( \nu = 13.56 \) MHz) PE-CVD apparatus (interelectrode distance = 6 cm). After preliminary optimization experiments, the total pressure, deposition time and RF-power were kept constant at 1.0 mbar, 60 min and 10 W, respectively. Fe(hfa)\(_2\)TMEDA, introduced in an external glass vessel, was vaporized at 65 °C by means of an oil bath, and its vapors were transported into the reaction chamber by an Ar flow (rate = 60 sccm). Gas lines were heated to 140 °C to prevent detrimental precursor condensation phenomena. Basing on preliminary experiments, four different deposition temperatures (100, 200, 300 and 400 °C) were adopted.

2.2. Characterization

XRD\(^2\) images were collected by a Dymax-RAPID X-ray micro-diffractometer with a cylindrical imaging plate detector, that allows data acquisition in the 2\( \theta \) ranges 0–160° (horizontally) and −45 to +45° (vertically) using CuK\(_{\alpha}\) radiation. Measurements were performed in reflection mode, adopting a collimator diameter of 300 \( \mu \)m and an exposure time of 30 min for each XRD\(^2\) pattern.

FE-SEM micrographs were acquired using a Zeiss SUPRA 40VP instrument, at a primary beam acceleration voltage of 10 kV.

XPS analyses were performed on a Perkin-Elmer \( \Phi \) 5600ci spectrometer, using a non-monochromatized AlK\(_{\alpha}\) excitation source (\( h\nu = 1486.6 \) eV), at working pressures lower than 10\(^{-8}\) mbar. Binding energy (BE, standard deviation = ±0.2 eV) shifts were corrected for charging assigning a value of 284.8 eV to the adventitious C1s signal. Ar\(^+\) sputtering was carried out at 3.0 kV with an Ar partial pressure of 5 \( \times \) 10\(^{-3}\) mbar. Peak fitting was performed by a least-squares procedure, adopting Gaussian–Lorentzian peak shapes. The atomic percentages (at.%) were calculated by peak integration using standard PHI V5.4A sensitivity factors.

SIMS measurements were carried out by means of a Cameca IMS 4F spectrometer adopting a 14.5 kV Cs\(^+\) primary beam (current = 20 nA), by negative secondary ion detection and electron gun charge compensation. Measurements were performed in high mass resolution configuration to avoid mass interference artifacts.

Samples for plane-view (pv) and cross-sectional (cs) TEM analyses were thinned down to electron transparency by polishing and ion-milling in a Balzers ion mill, starting with a 8 kV beam until perforation, continuing with a 5 kV beam for thinning and a 2 kV beam for final polishing. Conventional TEM, electron diffraction (ED) and high resolution (HR)-TEM analyses were performed using a Tecnai G2 30 UT microscope with a 0.17 nm point resolution, operated at 300 kV.

3. Results and discussion

In order to attain an insight into the system microstructure, with particular attention to the possible co-presence of various \( \alpha \)-Fe\(_2\)O\(_3\) polymorphs, XRD\(^2\) experiments were carried out (Fig. 1).

At the lowest deposition temperature (100 °C), no appreciable diffraction peaks could be detected, due to the reduced system crystallinity. In a different way, for temperatures between 200 and 400 °C, the recorded XRD\(^2\) images demonstrated the selective growth of pure \( \alpha \)-Fe\(_2\)O\(_3\). In particular, at 200 °C peaks located at 2\( \theta \) = 35.6° and 63.7°, related to \{110\} and \{300\} \( \alpha \)-Fe\(_2\)O\(_3\) (hematite, rhombohedral) reflections, were observed. Upon further increasing the growth temperature, patterns were characterized by the appearance of additional reflections at 2\( \theta \) = 24.1° \{012\}, 33.1° \{104\}, 40.8° \{113\}, 49.4° \{024\}, 54.0° \{116\}, 57.7° \{018\} and 62.3° \{214\}. As a general observation, at 300 °C the higher relative intensity of the \{110\} peak suggested the occurrence of a preferred orientation along this direction. This is confirmed by the corresponding XRD\(^2\) image, showing that Debye rings intensities are not homogeneously distributed along the rings.

Interestingly, the high \{110\}/\{104\} intensity ratio means that the Fe basal planes are perpendicular to the substrate. Since the conductivity parallel to the basal plane is higher than the one along the perpendicular direction, this can result in improved functional performances, especially in photoelectrochemical applications.

As already anticipated, one of the main goals of the present work is the doping of iron(II) oxide with fluorine. In this regard, the analysis of the surface and in-depth system composition as a function of the synthesis conditions was accomplished by the complementary use of XPS and SIMS. The chemical composition of the prepared systems has been preliminarily investigated by XPS survey scans (Fig. S1, ESI), showing the presence of Fe, O and F, along with the occurrence of C contamination.
The disappearance of carbon peaks to noise level after ~10 min of Ar⁺ erosion evidenced the high purity of the obtained systems. The progressive intensity decrease of the F1s peak for higher deposition temperatures suggests the possibility of tailoring the fluorine doping level as a function of the adopted conditions (see below). Fig. 2a displays the surface Fe2p signal for a specimen grown at 200 °C. For all the analyzed systems, the Fe2p peak position [BE(Fe2p3/2) = 711.3 eV; spin–orbit separation = 13.8 eV] and the low intensity of shake-up satellites were in good agreement with the presence of iron(III) oxide, free from other Fe-containing species (see also Fig. S2, ESI†). Regarding oxygen, the O1s peak (Fig. S3, ESI†) was characterized by the occurrence of two main contributions at BE = 530.0 eV, due to lattice oxygen in α-Fe₂O₃, and 531.8 eV, ascribed to chemisorbed hydroxyl groups.⁸,¹⁰,¹¹,²²,²³,³⁹ As exemplified by Fig. 2b, this signal could be fitted by means of two different components, located at 684.7 (I) and 688.5 eV (II), respectively. The first band was attributed to the incorporation of fluorine into the iron(III) oxide lattice, resulting in the formation of Fe–F bonds. As a matter of fact, similar BE peak positions have been reported for other metal oxides doped with fluorine.⁷,²⁵,²⁶,³⁸ On the other hand, the second contribution at BE = 688.5 eV could be related to undecomposed CFₓ precursor residuals.⁷,²⁵,²⁶,³⁸ It is worthwhile mentioning that this component completely disappeared after a few minutes of Ar⁺ erosion, suggesting that the presence of CFₓ moieties was confined to the outermost sample region. Conversely, component I, related to lattice fluorine, was retained even in the inner material layers (see Fig. S4, ESI†). Interestingly, the overall fluorine loading in the obtained Fe₂O₃ systems could be tailored as a function of the adopted deposition temperature, progressively decreasing from 12.0 at.% (at 100 °C) to 2.0 at.% (at 400 °C). A similar temperature dependence was observed for F doped Si and Co oxides synthesized by PE-CVD.²⁶,³³ To further investigate the material composition, in-depth SIMS measurements were carried out (Fig. 3). In general, all the samples presented a well-defined interface with the silicon substrate and an uniform composition throughout the entire thickness, as demonstrated by the O, Fe and F ionic yields. Remarkably, the almost parallel trend of fluorine with respect to iron signal pointed out to the achievement of a homogeneous Fe₂O₃ doping. To attain a relative estimation of fluorine concentration at different temperatures, the integral of F signal (IF) as a function of depth was estimated for the various specimens throughout their thickness. IF is in fact proportional to the areal density (expressed in at per cm²), i.e. fluorine concentration for unit surface. The results, plotted as ln(IF) in Fig. 3c, display a linear dependence on temperature, with a decay constant close to 50 ± 2 °C. This result highlights the
possibility of controlling F loading by tuning of the deposition temperature, an important issue to tailor the system properties affected by the dopant concentration.

Important preliminary clues on the system morphology as a function of the growth temperature were obtained by pv and cs FE-SEM analyses. Representative micrographs are displayed in Fig. 4. As a general observation, all specimens showed the presence of elongated nanostructures oriented almost perpendicularly to the substrate surface. In particular, the 100 °C sample was characterized by uniformly interconnected globular agglomerates (mean diameter = 70 ± 10 nm), resulting from the aggregation of vertically aligned columnar structures (length = 200 ± 10 nm). An increase of the substrate temperature to 200 °C produced a morphology evolution, resulting in the appearance of lamellar-like features with average width and length of 100 ± 30 and 350 ± 40 nm, respectively.

Whereas no dramatic difference in system nano-organization at 200 and 300 °C was observed, the specimen grown at 400 °C showed two different sets of nano-objects, namely rod-like structures (diameter = 20 ± 5 nm, length = 180 ± 20 nm) and lamellar structures (width = 30 ± 7 nm, length = 300 ± 20 nm). As a general observation, the nano-organization of the synthesized systems, suggesting a high active area, appears extremely promising in view of potential photocatalytic/sensing applications. In addition, nanostructures with reduced lateral size, like the present ones, offer the possibility of absorbing a significant light fraction while providing short charge carrier transport distances, minimizing thus recombination losses.5,15-17 Typical growth rate values, calculated as the ratio between the overall specimen thickness and the deposition duration (60 min, see above) ranged between 3 and 6 nm min⁻¹ in the adopted temperature range.

A further insight into the system nano-organization was gained by the use of advanced TEM analyses, which were carried out on representative samples grown at 300 and 400 °C. Selected
pv and cs bright field-TEM micrographs (Fig. 5) displayed the presence of columnar iron oxide structures, as already evidenced by FE-SEM analyses. ED patterns demonstrated that all grains exhibited the \(\alpha\)-Fe\(_2\)O\(_3\) (hematite) crystal structure,\(^7\) in agreement with XRD results (see Fig. 1).

The specimen grown at 300 °C shows irregularly shaped, vertically aligned grains. The ED ring pattern taken from the cs sample confirmed its polycrystalline nature. Regarding the sample deposited at 400 °C, two regions with different columnar structures could be observed. The region indicated by I in both the pv and cs images displays \(\alpha\)-Fe\(_2\)O\(_3\) columns growing nearly perpendicular with respect to the substrate surface. In a different way, in region II the columns grew inclined with respect to the substrate. The electron diffraction ring pattern recorded in pv orientation again clearly confirmed the sample polycrystalline nature. A diffraction pattern taken from a single grain in cs indicated its single crystal nature, free from extended defects.

To achieve more detailed information, HR-TEM imaging was undertaken on representative grains of both samples. Fig. 6a provides a pv TEM image of the specimen grown at 300 °C. Four inter-grown \(\alpha\)-Fe\(_2\)O\(_3\) grains in this sample are displayed in low-magnification in (b), and in high resolution in (c). All four grains are imaged along the [100] zone axis and display a rounded, irregular morphology. A typical cs grain structure, showing near to \(c\)-oriented growth and imaged along the \([1\overline{1}0]\) zone axis orientation, is reported in Fig. 7. Again, the highly irregular shape of the \(\alpha\)-Fe\(_2\)O\(_3\) crystal columns is clearly confirmed. HR-TEM images of the sample synthesized at 400 °C (Fig. 8), acquired in cs, demonstrate that the columns in region I generally show a more rounded morphology (here with a near
[001] growth direction), while the columns in region II evidenced a more sharply faceted saw-tooth shape (here with a near [120] growth direction).

4. Conclusions

This study was devoted to the development of a PE-CVD approach to fluorine doped iron(III) oxide nanosystems, using Fe(hfa)2Tmeda as a single-source molecular precursor for both iron and fluorine. The obtained materials, deposited at temperatures from 100 to 400 °C on Si(100) substrates under Ar/O2 plasmas, showed the presence of the sole α-Fe2O3 (hematite) polymorph, and were composed of elongated nanostructures, with shapes ranging from lamellar to rod-like as a function of the processing parameters. Notably, a uniform in-depth fluorine doping could be successfully achieved, with an overall content tunable as a function of the adopted growth temperature. In addition, (HR)-TEM results clearly indicated that a change in deposition temperature had a significant influence on the morphology of the deposited materials.

The possibility to fabricate iron oxide nanostructures with a selected fluorine doping and a tunable nanoscale organization opens intriguing perspectives in various technological fields, such as solid-state gas sensing, photoassisted catalytic processes and photoelectrochemical cells. In particular, the fundamental information on the interrelations between the synthesis conditions and material characteristics, provided by the present work, is of crucial importance for the subsequent investigation and tailoring of functional behavior. To this regard, further efforts in the optimization of the target materials for their technological exploitation will be the subject of our future work, devoting also particular attention to the introduction of functional activators (such as Cu, Ag and Au-based nanoparticles) to enhance the performances of the obtained iron(III) oxide nanostructures.

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Notes and references

37 Pattern no. 00-033-0664, JCPDS, 2000.